# NSN 5962-01-293-7710

Memory Microcircuit - Page 1 of 1

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# **Body Length:**

Between 0.755 inches and 0.785 inches

## **Body Width:**

0.302 inches

# **Body Height:**

Between 0.145 inches and 0.175 inches

# **Maximum Power Dissipation Rating:**

332.8 milliwatts

#### **Operating Tempurature Range:**

+0.0/+70.0 degrees celsius

## Storage Tempurature Range:

-65.0/+150.0 degrees celsius

#### **Features Provided:**

Bipolar and programmable and schottky and w/enable

#### **Inclosure Material:**

# Ceramic and glass

# Inclosure Configuration:

Dual-in-line

## **Output Logic Form:**

Transistor-transistor logic

## Input Circuit Pattern:

6 input

#### **Terminal Surface Treatment:**

Solder

## Voltage Rating And Type Per Characteristic:

7.0 volts power source

## **Time Rating Per Chacteristic:**

50.00 nanoseconds propagation delay time, low to high level output and 50.00 nanoseconds propagation delay time, high to low level output

#### Memory Device Type:

Rom

#### **Terminal Type And Quantity:**

16 printed circuit

#### Shelf Life:

N/a

# Unit Of Measure:

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## Demilitarization:

Yes - demil/mli

# Fiig:

A458a0

